## NSN 5961-01-039-8730

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-039-8730 **Inclosure Material:** Metal **Overall Length:** 0.460 inches **Overall Height:** 0.460 inches **Overall Diameter:** 0.687 inches **End Application:** Arts2a, automated radar terminal system 2a, dtfa01-90c-00057 **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 170.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 15.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector absolute **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** No

## **NSN 5961-01-039-8730** Transistor - Page 2 of 2



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